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Sheet 1 of 1

Complete if Known

Application Number	08/902133
Filing Date	July 29, 1997
First Named Inventor	Forbes, Leonard
Group Art Unit	2815
Examiner Name	Eckert II, George

Attorney Docket No: 00303.356US1

US PATENT DOCUMENTS

Examiner Initial *	USP Document Number	Publication Date	Name of Patentee or Applicant of cited Document	Class	Subclass	Filing Date If Appropriate
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OTHER DOCUMENTS -- NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
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EXAMINER

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DATE CONSIDERED

12/30/02

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